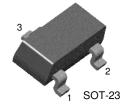


FJV4109R

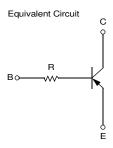
Switching Application (Bias Resistor Built In)

- Switching circuit, Inverter, Interface circuit, Driver Circuit
- Built in bias Resistor (R=4.7KΩ)
- Complement to FJV3109R



1. Base 2. Emitter 3. Collector





PNP Epitaxial Silicon Transistor

Absolute Maximum Ratings T_a=25°C unless otherwise noted

Symbol	Parameter	Value	Units
V _{CBO}	Collector-Base Voltage	-40	V
V_{CEO}	Collector-Emitter Voltage	-40	V
V _{EBO}	Emitter-Base Voltage	-5	V
I _C	Collector Current	-100	mA
P _C	Collector Power Dissipation	200	mW
T _J	Junction Temperature	150	°C
T _{STG}	Storage Temperature	-55 ~ 150	°C

Electrical Characteristics $T_a=25$ °C unless otherwise noted

Symbol	Parameter	Test Condition	Min.	Тур.	Max.	Units
BV _{CBO}	Collector-Base Breakdown Voltage	I_{C} = -100 μ A, I_{E} =0	-40			V
BV _{CEO}	Collector-Emitter Breakdown Voltage	$I_C = -1 \text{mA}, I_B = 0$	-40			V
I _{CBO}	Collector Cut-off Current	V_{CB} = -30V, I_{E} =0			-0.1	μΑ
h _{FE}	DC Current Gain	V_{CE} = -5V, I_{C} = -1mA	100		600	
V _{CE} (sat)	Collector-Emitter Saturation Voltage	I_C = -10mA, I_B = -1mA			-0.3	V
C _{ob}	Output Capacitance	V _{CB} = -10V, I _E =0 f=1MHz		5.5		pF
f _T	Current Gain Bandwidth Product	V_{CE} = -10V, I_{C} = -5mA		200		MHz
R	Input Resistor		3.2	4.7	6.2	ΚΩ

I_C = 10I_B R = 4.7k

Typical Characteristics

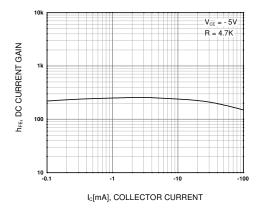


Figure 2. Collector-Emitter Saturation Voltage

I_C[mA], COLLECTOR CURRENT

V_{CE}(sat)[mV], SATURATION VOLTAGE



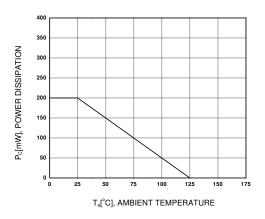
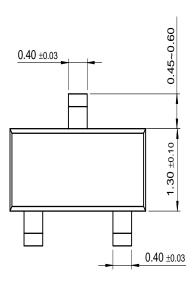


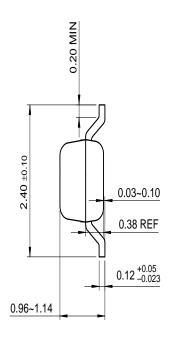
Figure 3. Power Derating

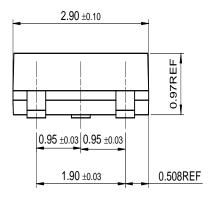
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Package Dimensions

SOT-23







Dimensions in Millimeters

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CROSSVOLT™	FRFET™	MicroPak™	QFET™	SuperSOT™-8
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EcoSPARK™	GTO™	MSX™	QT Optoelectronics™	TinyLogic™
E ² CMOS™	HiSeC™	MSXPro™	Quiet Series™	TruTranslation™
EnSigna™	I^2C^{TM}	OCXTM	RapidConfigure™	UHC™
Across the board.	. Around the world.™	OCXPro™	RapidConnect™	UltraFET®
The Power Franchise™		OPTOLOGIC [®]	SILENT SWITCHER®	VCX™
Programmable Active Droop™		OPTOPLANAR™	SMART START™	

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Rev. I1

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Definition of Terms

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